

PSMN040-100MSE

N-channel 100 V 36.6 mΩ standard level MOSFET in LFPAK33 designed specifically for high power PoE applications

26 March 2013

Product data sheet

1. General description

New standards and proprietary approaches are enabling Power-over-Ethernet (PoE) systems capable of delivering up to 90W to each powered device (PD). Such solutions place increased demands on the power sourcing equipment (PSE) in terms of "soft-start", thermal management and power density requirements.

2. Features and benefits

- Enhanced forward biased safe operating area for superior linear mode operation
- Low Rdson for low conduction losses
- Ultra reliable LFPAK33 package for superior thermal and ruggedness performance
- Very low I_{DSS}

3. Applications

- High power PoE applications (60W and higher)
- IEEE802.3at and proprietary solutions

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	-	100	V	
I _D	drain current	T _j = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	-	-	30	Α	
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	91	W	
Static charact	Static characteristics						
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 10 \text{ A}; T_j = 25 \text{ °C};$ Fig. 13	-	29.4	36.6	mΩ	
Dynamic char	acteristics						
Q_{GD}	gate-drain charge	V _{GS} = 10 V; I _D = 10 A; V _{DS} = 50 V;	-	10.7	-	nC	
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	30	-	nC	
Avalanche Ruggedness							
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 30 A; V_{sup} ≤ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3	-	-	54	mJ	



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simpl	ified outline	Graph	ic symbol
1	S	source				D I
2	S	source				
3	S	source				G T T
4	G	gate				mbb076 S
mb	D	mounting base; connected to drain	LI	FPAK33 (SOT1210)		

6. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
PSMN040-100MSE	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN040-100MSE	M40E10

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 175$ °C; $R_{GS} = 20$ kΩ	-	100	V
V_{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 1</u>	-	30	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	21	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$; Fig. 4	-	121	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	91	W
T _{stg}	storage temperature		-55	175	°C

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Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	70	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	121	Α
Avalanche	Ruggedness				'	
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_{D} = 30 A; $V_{sup} \le$ 100 V; R_{GS} = 50 Ω; unclamped; Fig. 3		-	54	mJ

[1] Continuous current is limited by package.

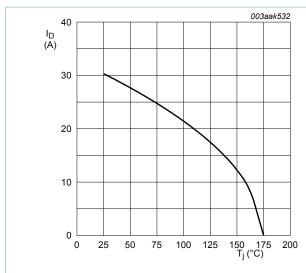


Fig. 1. Continuous drain current as a function of mounting base temperature

 $V_{GS} \ge 10V$

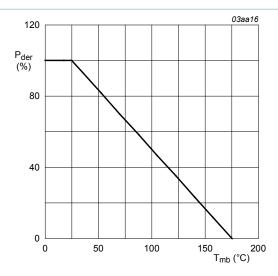


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

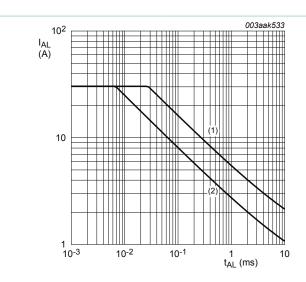


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j \ (init)} = 25^{\circ}C$$
; (2) $T_{j \ (init)} = 100^{\circ}C$

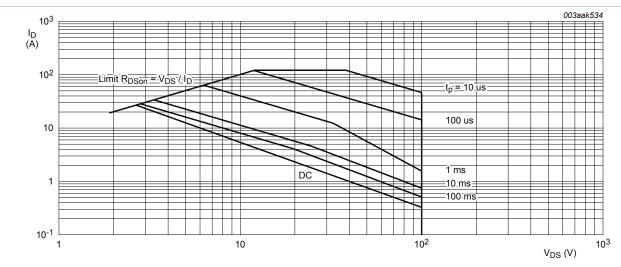


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

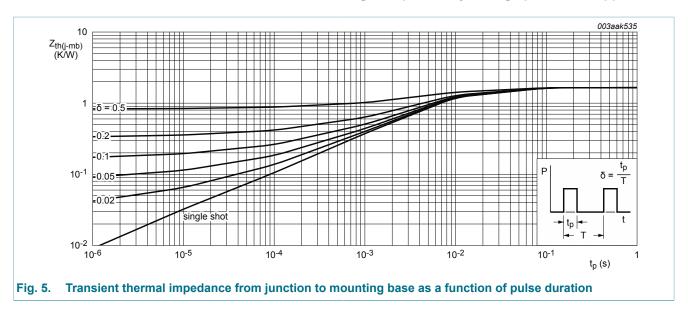
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	1.44	1.65	K/W

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
(DIX)DOO	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 ^{\circ}C$	100	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 10; Fig. 11	2.3	3.3	4	V
	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10	-	-	4.6	V	
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 10	1	-	-	V
I _{DSS} drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.05	1	μA	
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	10	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 10 A; T _j = 100 °C; Fig. 12; Fig. 13	-	-	66	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 175 °C; Fig. 12; Fig. 13	-	-	99	mΩ
		V_{GS} = 10 V; I_{D} = 10 A; T_{j} = 25 °C; Fig. 13	-	29.4	36.6	mΩ
R_G	gate resistance	f = 10 MHz	-	1.65	-	Ω

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics		l l			
Q _{G(tot)} total	total gate charge	I _D = 10 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	30	-	nC
		$I_D = 0 \text{ A; } V_{DS} = 0 \text{ V; } V_{GS} = 10 \text{ V;}$ $T_j = 25 \text{ °C}$	-	24	-	nC
Q _{GS}	gate-source charge	I _D = 10 A; V _{DS} = 50 V; V _{GS} = 10 V;	-	7.6	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	4.5	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	3.1	-	nC
Q_{GD}	gate-drain charge		-	10.7	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 10 A; V _{DS} = 50 V; T _j = 25 °C; Fig. 14; Fig. 15	-	5.6	-	V
C _{iss}	input capacitance	V _{DS} = 50 V; V _{GS} = 0 V; f = 1 MHz;	-	1470	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	-	110	-	pF
C _{rss}	reverse transfer capacitance		-	80	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 50 V; R_L = 5 Ω ; V_{GS} = 10 V;	-	8.3	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	14.1	-	ns
t _{d(off)}	turn-off delay time		-	18.7	-	ns
t _f	fall time		-	13	-	ns
Source-dra	in diode		1	,		
V _{SD}	source-drain voltage	I _S = 20 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u>	-	0.82	1.2	V
t _{rr}	reverse recovery time	$I_S = 10 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	41	-	ns
Q _r	recovered charge	$V_{DS} = 50 \text{ V}; T_j = 25 \text{ °C}$	-	75	-	nC

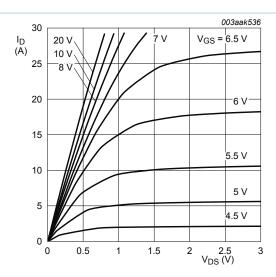


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



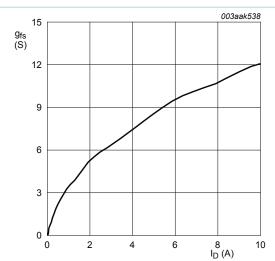


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25$$
°C; $V_{DS} = 10V$

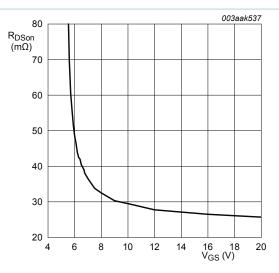


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25$$
°C; $I_D = 10A$

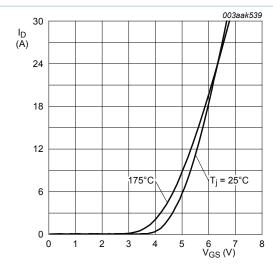


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

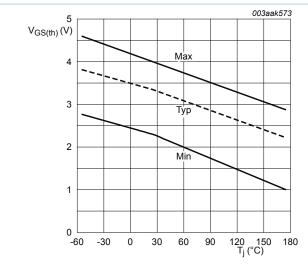


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; \ V_{DS} = V_{GS}$$

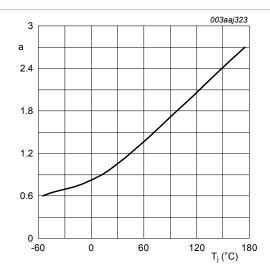


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}C)}}$$

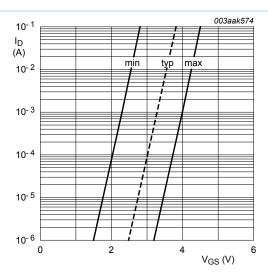


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25 \,^{\circ}C; V_{DS} = 5V$$

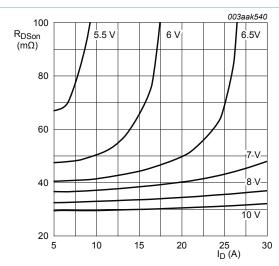


Fig. 13. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25$$
° C

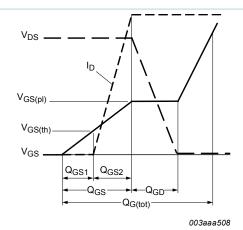


Fig. 14. Gate charge waveform definitions

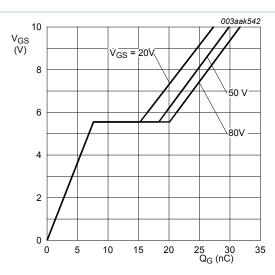


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 10A$$

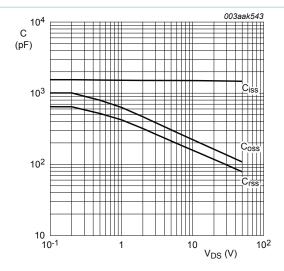


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$

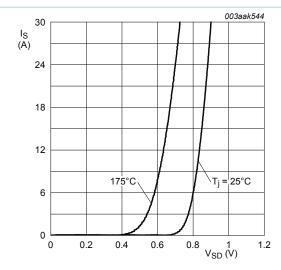
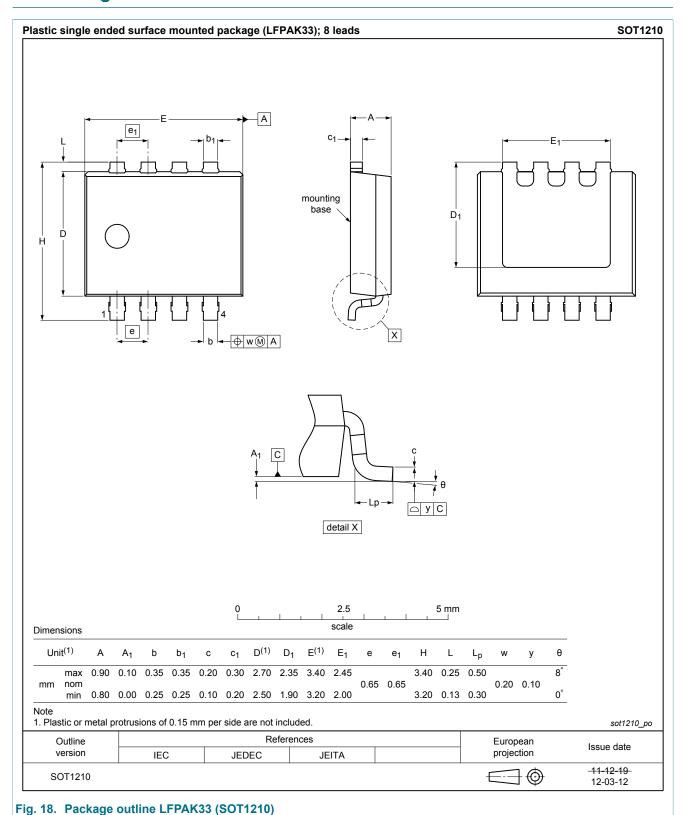


Fig. 17. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$

11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
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